

U.S. Department of Commerce, Patent and Trademark		Atty. Docket No.			Application No.			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		SNDK.268US1			10/665,828			
		Applicant(s)			Conf. No.			
Use several sheets if necessary)		Raul-Adrian Cernea and Yan Li			6022			
JUN 01 2004		Filing Date			Group			
		September 17, 2003			2818			
<b>U.S. Patent Documents</b>								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
DL	1	4,785,427	Nov. 15, 1988	Young				
	2	5,093,806	Mar. 3, 1992	Tran				
	3	5,245,571	Sep. 14, 1993	Takahashi				
	4	5,595,924	Jan. 21, 1997	Yuan et al.				
	5	5,860,082	Jan. 12, 1999	Smith et al.				
	6	5,872,739	Feb. 16, 1999	Womack				
	7	5,949,720	Sep. 4, 1999	Brady				
DL	8	6,097,638	Aug. 1, 2000	Himeno et al.				
<b>U.S. Published Patent Application Documents</b>								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
<b>Foreign Patent Documents</b>								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
DL	9	1134746 A2	Sep. 19, 2001	Europe				
DL	10	WO 02/069340	Sep. 6, 2002	WIPO				
<b>OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)</b>								
DL	11	International Search Report corresponding to PCT/US03/30133, International Searching Authority, European Patent Office, filed September 18, 2003, 4 pages						
DL	12	Eitan et al., "NROM: A Novel Localized Trapping 2-Bit Nonvolatile Memory Cell," IEEE Electron Device Letters, vol. 21, no. 11, Nov. 2000, pp. 543-545						
Examiner	<i>DL</i>		Date Considered	9/04				
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.								